BCX19



SEMICONDUCTOR®

# BCX19

# **NPN Medium Power Transistor**

- This device is designed for general purpose amplifiers.
- Sourced from process 38.



1. Base 2. Emitter 3. Collector

# Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

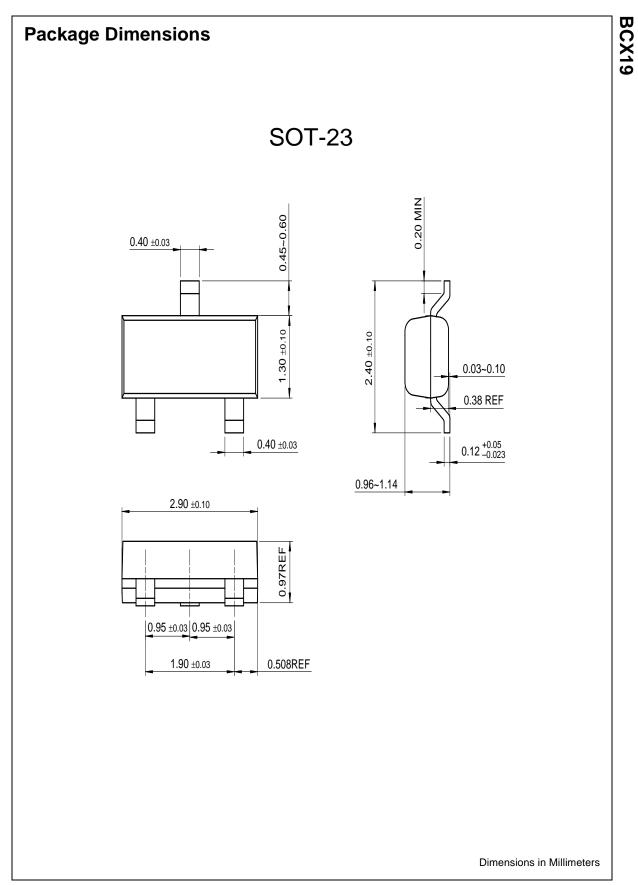
Symbol	Para	meter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage		45	V
V <sub>CBO</sub>	Collector-Base Voltage		50	V
V <sub>EBO</sub>	Emitter-Base Voltage		5.0	V
I <sub>C</sub>	Collector current	- Continuous	500	mW
T <sub>J</sub> , T <sub>stq</sub>	Junction and Storage Tempera	ture	-55 ~ +150	°C

# Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Characte	eristics					
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$	45			V
V <sub>(BR)CES</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 10 \mu {\rm A}, I_{\rm C} = 0$	50			V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 20V, I_E = 0$ $V_{CB} = 20V, I_E = 0, T_A = 150^{\circ}C$			100 5.0	nA μA
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = 5.0V, I_{C} = 0$			10	μΑ
On Characte	eristics	·		•	•	
h <sub>FE</sub>	DC Current Gain	$I_{C} = 100 \text{mA}, V_{CE} = 1.0 \text{V}$ $I_{C} = 300 \text{mA}, V_{CE} = 1.0 \text{V}$ $I_{C} = 500 \text{mA}, V_{CE} = 1.0 \text{V}$	100 70 40		600	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA			0.62	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 500mA, V <sub>CE</sub> = 1.0V			1.2	V

## Thermal Characteristics $T_A=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.	Units
PD	Total Device Dissipation Derate above 25°C	300 2.4	mW mW/°C
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	417	°C/W



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### **PRODUCT STATUS DEFINITIONS**

### **Definition of Terms**

Datasheet Identification

Product Status

Definition2H6 ord9lif)6002 ii pier(o)1.80 se f2 (tiel)14 ii0e